NSN 5962-01-370-6638



Memory Microcircuit - Page 1 of 2	
View Online at https://aerobasegroup.com/nsn/5962-01-370-6638	
Body Length:	
1.490 inches	
Body Width:	
Between 0.500 inches and 0.610 inches	
Body Height:	
0.217 inches	
Maximum Power Dissipation Rating:	
825.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Electrostatic sensitive and w/disable and w/enable and ultraviolet erasable and mo	pnolithic
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
18 input	
Criticality Code Justification:	
Feat	
Case Outline Source And Designator:	
D-10 mil-m-38510	
Current Rating Per Characteristic:	
150.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
-0.6 volts power source and 6.5 volts power source	
Capitance Rating Per Characteristic:	
7.00 input picofarads and 12.00 output picofarads	
Time Rating Per Chacteristic:	

250.00 nanoseconds access

Memory Device Type:

Eprom

Special Features:

Nuclear hardness critical item

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

NSN 5962-01-370-6638

Memory Microcircuit - Page 2 of 2



Terminal Type A	and Quantity	/ :
-----------------	--------------	------------

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0